

Page 2, delete the whole paragraph starting with line 6 and replace it with the following new paragraph.

In the aforementioned light-emitting device 200, the barrier layers 162 are made substantially uniform in thickness so as to be generally in a range of 70 to 80Å. Moreover, from the point of view of improvement in color purity, the intermediate layer 14 of InGaN is provided, and the n-type clad layer 15 having the same thickness and composition as each of the barrier layers 162 is also formed.

A3

Page 2, delete the whole paragraph starting with line 13 and replace it with the following new paragraph.

In the group III nitride compound semiconductor light-emitting device such as the aforementioned light-emitting device 200, or the like, there is a problem in that the effect of confining carriers in the light-emitting layer 16 against the high carrier density n<sup>+</sup> layer 13 is unable to be obtained sufficiently because the thickness of the n-type clad layer 15 under the light-emitting layer 16 is substantially equal to the thickness of each of the barrier layers 162, and therefore light-emitting efficiency is low in spite of very good color purity.

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Page 4, delete the whole paragraph starting with line 9 and replace it with the following new paragraph.

According to the means of the present invention, carriers contributing to light emission can hardly run away from the light-emitting layer 16 toward the high carrier density

A5

cont. n<sup>+</sup> layer 13 because the n-type clad layer 15 thicker than each of the barrier layers is formed to be in contact with the light-emitting layer 16 of the multilayer quantum well structure.

A5 That is, the carrier confinement effect can be obtained sufficiently by the n-type clad layer 15, so that light-emitting efficiency is improved:

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Page 6, delete the whole paragraph starting with line 13 and replace it with the following new paragraph.

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A6 Fig. 2 shows a sectional view showing the structure of a group III nitride compound semiconductor light-emitting device 200.

See the attached Appendix for the changes made to effect the above specification.

IN THE CLAIMS:

Please cancel claims 2 and 3 without prejudice.

Please enter the following amended claim: